# Potential Sweep Methods (Ch. 6)

Nernstian (reversible) systems
Totally irreversible systems
Quasireversible systems
Cyclic voltammetry
Multicomponent systems & multistep charge transfers

# **Introduction**

Linear sweep voltammetry (LSV)

Cyclic voltammetry (CV)

#### Nernstian (reversible) systems

#### Solution of the boundary value problem

O + ne = R (semi-infinite linear diffusion, initially O present)

$$E(t) = E_i - vt$$

Sweep rate (or scan rate): v (V/s)

Rapid e-transfer rate at the electrode surface

$$C_O(0, t)/C_R(0, t) = f(t) = \exp[nF(E_i - vt - E^{0'})/RT]$$

$$i = nFAC_O^*(\pi D_O^*\sigma)^{1/2}\chi(\sigma t)$$

$$\sigma = (nF/RT)v$$

#### **Peak current and potential**

Peak current:  $\pi^{1/2}\chi(\sigma t) = 0.4463$ 

$$i_p = 0.4463 (F^3/RT)^{1/2} n^{3/2} A D_O^{1/2} C_O^* v^{1/2}$$

At 25°C, for A in cm<sup>2</sup>,  $D_O$  in cm<sup>2</sup>/s,  $C_O^*$  in mol/cm<sup>3</sup>, v in  $V/s \rightarrow i_p$  in amperes

$$i_p = (2.69 \text{ x } 10^5) n^{3/2} A D_O^{1/2} C_O^* v^{1/2}$$

Peak potential, E<sub>p</sub>

$$E_p = E_{1/2} - 1.109(RT/nF) = E_{1/2} - 28.5/n$$
 mV at 25°C

Half-peak potential, E<sub>p/2</sub>

$$E_{p/2} = E_{1/2} + 1.09(RT/nF) = E_{1/2} + 28.0/n$$
 mV at 25°C

 $E_{1/2}$  is located between  $E_p$  and  $E_{p/2}$ 

$$|E_p - E_{p/2}| = 2.20(RT/nF) = 56.5/n$$
 mV at °C

For reversible wave,  $\underline{E}_p$  is independent of scan rate,  $\underline{i}_p$  is proportional to  $v^{1/2}$ 

#### **Spherical electrodes and UMEs**

Spherical electrode (e.g., a hanging mercury drop)

$$i = i(plane) + nFAD_OC_O*\phi(\sigma t)/r_0$$

 $\phi(\sigma t)$ : tabulated function (Table 6.2.1)

For large v in conventional-sized electrode  $\rightarrow$  i(plane) >> 2<sup>nd</sup> term Same for hemispherical & UME at fast scan rate

For UME at very small v:  $r_0$  is small  $\rightarrow$  i(plane)  $<< 2^{nd}$  term

- → voltammogram is a steady-state response independent of v
- $\rightarrow$  v << RTD/nFr<sub>0</sub><sup>2</sup>

 $r_0 = 5 \ \mu m$ ,  $D = 10^{-5} \ cm^2/s$ ,  $T = 298 \ K \rightarrow steady-state voltammogram at <math>v < 1 \ V/s$   $r_0 = 0.5 \ \mu m \rightarrow steady-state behavior up to <math>10 \ V/s$ 

Transition from typical peak-shaped voltammograms at fast v to steady-state voltammograms at small v

cf. For potential sweep (Ch.1) Linear potential sweep with a sweep rate v (in V/s)

$$E = vt$$

$$E = E_R + E_C = iR_s + q/C_d$$
 
$$vt = R_s(dq/dt) + q/C_d$$
 
$$If q = 0 \text{ at } t = 0, \qquad i = vC_d[1 - exp(-t/R_sC_d)]$$

- Current rises from 0 and attains a steady-state value (vC<sub>d</sub>):  $\underline{\text{measure C}}_{\underline{d}}$ 

### Effect of double-layer capacitance & uncompensated resistance

Charging current at potential sweep

$$|i_c| = AC_d v$$

Faradaic current measured with baseline of  $i_c$  $i_p$  varies with  $v^{1/2}$ ,  $i_c$  varies with  $v \rightarrow \underline{i_c}$  more important at faster v

$$|i_c|/i_p = [C_d v^{1/2} (10^{-5})]/[2.69 n^{3/2} D_O^{1/2} C_O^*]$$

At high v & low  $C_0^* \rightarrow$  severe distortion of the LSV wave

 $R_u$  cause  $E_p$  to be a function of v

#### **Totally irreversible systems**

#### Solution of the boundary value problem

 $\zeta_{\rm f}$ 

Totally irreversible one-step, one-electron reaction:  $O + e \rightarrow R$ 

$$i/FA = D_O(\partial C_O(x, t)/\partial x)_{x=0} = k_f(t)C_O(0, t)$$

Where 
$$k_f = k^0 e^{-\alpha f(E(t) - E0')}$$
,  $E(t) = E_i - vt$ 

$$\longrightarrow$$

$$k_f(t)C_O(0, t) = k_{fi}C_O(0, t)e^{bt}$$

Where 
$$b = \alpha f v \& k_{fi} = k^0 exp[-\alpha f(E_i - E^{0'})]$$

$$i = FAC_O * D_O^{1/2} v^{1/2} (\alpha F/RT)^{1/2} \chi(bt)$$

 $\chi$ (bt) (Table 6.3.1). i varies with  $v^{1/2}$  and  $C_O^*$ 

For spherical electrodes

$$i = i(plane) + FAD_0C_0*\phi(bt)/r_0$$

#### **Peak current and potential**

Maximum  $\chi(bt)$  at  $\pi^{1/2}\chi(bt) = 0.4958$ Peak current

$$i_p = (2.99 \text{ x } 10^5)\alpha^{1/2}AC_O^*D_O^{1/2}v^{1/2}$$

n-electron process with RDS: n in right side

Peak potential

$$\alpha(E_p-E^{0'}) + (RT/F)ln[(\pi D_O b)^{1/2}/k^0] = -0.21(RT/F) = -5.34 \ mV \ at \ 25^{\circ}C$$

Or

$$\begin{split} E_p &= E^{0'} - (RT/\alpha F)[0.780 + ln(D_O^{1/2}/k^0) + ln(\alpha Fv/RT)^{1/2}] \\ &|E_p - E_{p/2}| = 1.857RT/\alpha F = 47.7/\alpha \ mV \ at \ 25^{\circ}C \end{split}$$

 $E_p$ : ftn of  $v \rightarrow$  for reduction, 1.15RT/ $\alpha$ F (or 30/ $\alpha$  mV at 25°C) negative shift for tenfold increase in v

$$i_p = 0.227 FAC_O^* k^0 exp[-\alpha f(E_P - E^{0'})]$$

 $\rightarrow$  i<sub>p</sub> vs. E<sub>p</sub> – E<sup>0'</sup> plot at different v: slope of – $\alpha$ f and intercept proportional to k<sup>0</sup> n-electron process with RDS: n in right side

#### **Quasireversible systems**

For one-step, one-electron system

$$O + e = R$$

For the quasireversible one-step, one-electron case (5.5.3, p. 191)

$$i/FA = D_O(\partial C_O(x, t)/\partial x)_{x=0} = k_f C_O(0, t) - k_b C_R(0, t)$$

Where 
$$k_f = k^0 e^{-\alpha f(E - E0')} \& k_b = k^0 e^{(1 - \alpha)f(E - E0')}, f = F/RT$$

The shape of peak & peak parameters  $\rightarrow$  ftns of  $\alpha$  &  $\wedge$ 

Or for 
$$D_O = D_R = D$$

Current

 $\Psi(E)$  (Fig. 6.4.1):  $\Lambda > 10 \rightarrow$  approach to the reversible

### **Cyclic voltammetry**

$$\begin{array}{ll} (0 < t \leq \lambda) & \quad E = E_i - vt \\ (t > \lambda) & \quad E = E_i - 2v\lambda + vt \end{array}$$

## Nernstian systems

i-t curve at different  $E_{\lambda}$ 

i-E curve (CV) at different  $E_{\lambda}$ 

(1)  $E_{\lambda}$  (1)  $E_{1/2} - 90/n$ , (2)  $E_{1/2} - 130/n$ , (3)  $E_{1/2} - 200/n$  mV, (4) <u>after  $i_{pc} \rightarrow 0$ </u>

 $i_{pa}/i_{pc} = 1$  for nernstian regardless of scan rate,  $E_{\lambda}$  (> 35/n mV past  $E_{pc}$ ), D

 $i_{pa}/i_{pc} \rightarrow kinetic information$ If actual baseline cannot be determined,

$$i_{pa}/i_{pc} = (i_{pa})_0/i_{pc} + 0.485(i_{sp})_0/i_{pc} + 0.086$$

Reversal charging current is same as forward scan, but opposite sign

$$\Delta E_p = E_{pa} - E_{pc} \sim 2.3RT/nF$$
 (or 59/n mV at 25°C)

#### **Quasireversible systems**

Wave shape &  $\Delta E_p \rightarrow$  ftns of v,  $k^0$ ,  $\alpha$  &  $E_{\lambda}$ If  $E_{\lambda} > 90/n$  mV beyond cathodic peak  $\rightarrow$  small  $E_{\lambda}$  effect

$$\Psi = \Lambda \pi^{-1/2} = [k^0 (D_0/D_R)^{\alpha}]/(\pi D_0 f v)^{1/2}$$

(1) 
$$\Psi = 0.5$$
,  $\alpha = 0.7$ , (2)  $\Psi = 0.5$ ,  $\alpha = 0.3$ , (3)  $\Psi = 7$ ,  $\alpha = 0.5$ , (4)  $\Psi = 0.25$ ,  $\alpha = 0.5$ 

For  $0.3 < \alpha < 0.7 \rightarrow \Delta E_p$  independent of  $\alpha$ ; depend only on  $\Psi$   $\rightarrow$  estimating  $k^0$  in quasireversible systems

 $\Delta E_p \text{ vs. } v \rightarrow \Delta E_p \text{ vs } \Psi$ 

# Multicomponent systems & Multistep charge transfers

O & O' system

Method for obtaining baselines Constant E after 1

Sweep stop beyond E<sub>p1</sub>

In vivo applications of LSV & CV e.g., rat brain